

ST20120C STB20120C

Technical Data Data Sheet N1368, Rev. A

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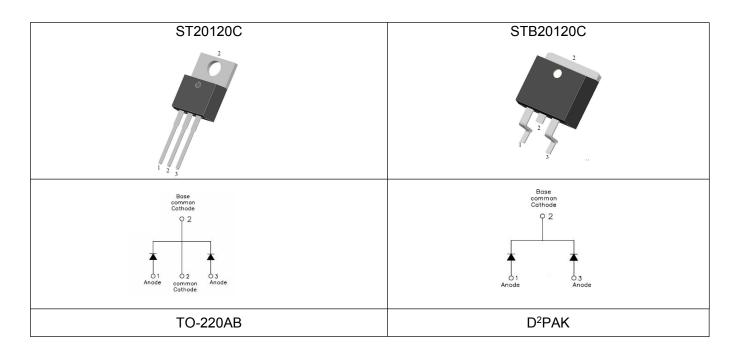
ST20120C/STB20120C SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 150 °C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	V _{RRM}	-		
Working Peak Reverse Voltage	VRWM		120	V
DC Blocking Voltage	V _R			
Average Restified Featured Current		50% duty cycle @Tc=105°C,	10(Per Leg)	^
Average Rectified Forward Current	IF (AV)	rectangular wave form	20(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	150	А

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ST20120C STB20120C

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 5A, Pulse, TJ = 25℃ @ 10A, Pulse, TJ = 25℃	0.60 0.81	- 0.90	V
	V _{F2}	@ 5A, Pulse, TJ = 25℃ @ 10A, Pulse, TJ = 125℃	0.50 0.61	- 0.72	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25℃	0.02	0.7	mA
	I _{R2}	@V _R = rated V _R , T _J = 125℃	5	45	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	400	-	pF

* Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

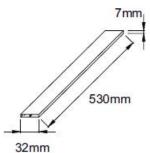
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	Rejc	DC operation	2.8	°C/W

Tube Specification

Device	Package	Weight	Shipping
ST20120C	TO-220AB	2.0	50pcs / tube
STB20120C	D ² PAK	1.85	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AB)

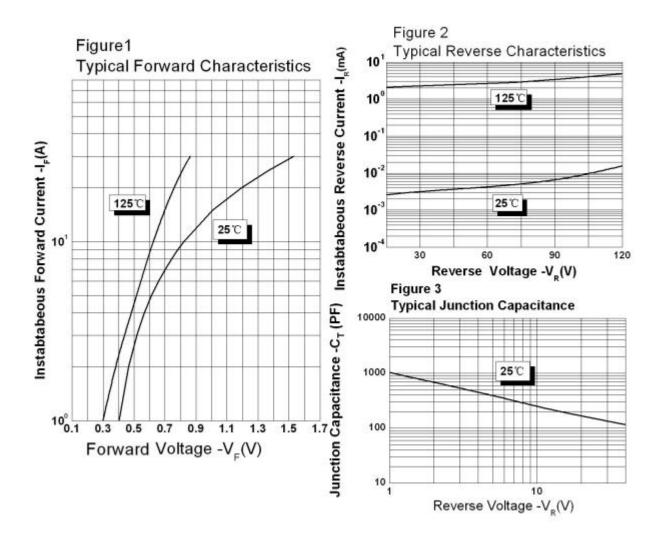








Ratings and Characteristics Curves





ST20120C STB20120C



Marking Diagram

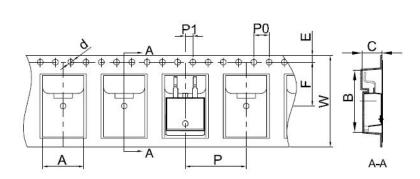


STB	201	200
SSG	X)	XXX
		C
TT	П	TT

Where XXXXX is YYWWL

ST	= Device Type
B	= Package type
20	= Forward Current (20A)
120	= Reverse Voltage (120V)
C	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
	= vveek = Lot Number
-	Molding resin
Cautions:	Epoxy resin UL:94V-0

Carrier Tape Specification D2PAK



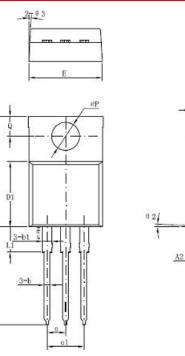
SYMBOL	Millimeters		
STWBOL	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	



ST20120C STB20120C



Mechanical Dimensions TO-220AB

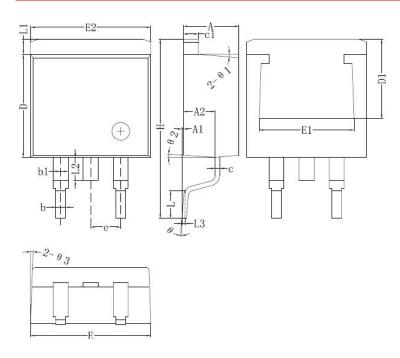


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Symbol	Dimensions in millimeters			
	Min	Typical	Max	
A	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
e		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

Mechanical Dimensions D²PAK



Symbol	Dimensions in millimeters			
_	Min.	Typical	Max.	
A	4.47	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
e3		4°		

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ST20120C STB20120C



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